

74HC05

HEX INVERTERS WITH OPEN DRAIN OUTPUTS

## Description

The 74HC05 provides provides six independent inverters with open drain outputs. The device is designed for operation with a power supply range of 2.0V to 6.0V.

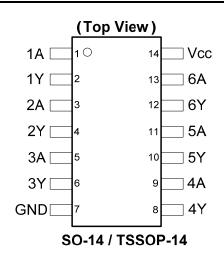
The gates perform the Boolean function:

 $\mathsf{Y}=\overline{\mathsf{A}}$ 

## Features

- Wide Supply Voltage Range from 2.0V to 6.0V
- Sinks 4mA at  $V_{CC}$  = 4.5V
- CMOS Low Power Consumption
- Schmitt Trigger Action at All Inputs
- ESD Protection Exceeds JESD 22
  - 200-V Machine Model (A115-A)
  - 2000-V Human Body Model (A114-A)
  - Exceeds 1000-V Charged Device Model (C101C)
- Range of Package Options SO-14 and TSSOP-14
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

## **Pin Assignments**



### Applications

- General Purpose Logic
  - Wide array of products such as:
    - PCs, Networking, Notebooks, Netbooks
    - Computer Peripherals, Hard Drives, CD/DVD ROM
    - TV, DVD, DVR, Set Top Box

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

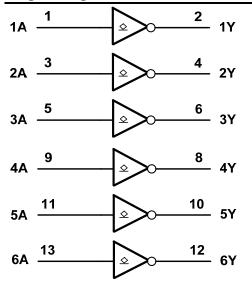
See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.</li>



# **Pin Descriptions**

| Pin<br>Number | Pin Name        | Function       |
|---------------|-----------------|----------------|
| 1             | 1A              | Data Input     |
| 2             | 1Y              | Data Output    |
| 3             | 2A              | Data Input     |
| 4             | 2Y              | Data Output    |
| 5             | 3A              | Data Input     |
| 6             | 3Y              | Data Output    |
| 7             | GND             | Ground         |
| 8             | 4Y              | Data Output    |
| 9             | 4A              | Data Input     |
| 10            | 5Y              | Data Output    |
| 11            | 5A              | Data Input     |
| 12            | 6Y              | Data Output    |
| 13            | 6A              | Data Input     |
| 14            | V <sub>CC</sub> | Supply Voltage |

# Logic Diagram



# **Function Table**

| Input | Output |
|-------|--------|
| Α     | Y      |
| Н     | L      |
| L     | Z      |



# **Absolute Maximum Ratings** (Note 4) (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Symbol   | Description  | Rating       | Unit |
|--|--|--------------|------|
| ESD HBM  | Human Body Model ESD Protection  | 2            | KV   |
| ESD CDM  | Charged Device Model ESD Protection                                      | 1            | KV   |
| ESD MM   | Machine Model ESD Protection   | 200          | V    |
| V <sub>CC</sub>  | Supply Voltage Range   | -0.5 to +7.0 | V    |
| VI   | Input Voltage Range (Note 5)   | -0.5 to +7.0 | V    |
| I <sub>IK</sub>  | Input Clamp Current VI < -0.5V or Vi > V <sub>CC</sub> + 0.5V            | ±20          | mA   |
| $I_{OK}$ Output Clamp Current $V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$ |  | ±20          | mA   |
| lo   | Continuous Output Current - 0.5V < V <sub>O</sub> V <sub>CC</sub> + 0.5V | +/- 25       | mA   |
| Icc  | Continuous Current Through V <sub>CC</sub>                               | 50           | mA   |
| I <sub>GND</sub>   | Continuous Current Through GND   | -50          | mA   |
| T <sub>J</sub> Operating Junction Temperature                        |  | -40 to +150  | °C   |
| T <sub>STG</sub>   | Storage Temperature  | -65 to +150  | °C   |
| Ртот   | Total Power Dissipation  | 500          | mW   |

Notes: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

5. Input Voltage cannot exceed  $V_{CC}$  to the extent the Maximum clamp current is exceeded

## Recommended Operating Conditions (Note 6) (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Symbol          | Parameter                                | Conditions             | Min | Max             | Unit |
|-----------------|--|------------------------|-----|-----------------|------|
| V <sub>CC</sub> | Supply Voltage                           |                        | 2.0 | 6.0             | V    |
| VI              | Input Voltage                            |                        | 0   | Vcc             | V    |
| Vo              | Output Voltage                           |                        | 0   | V <sub>CC</sub> | V    |
|                 |  | V <sub>CC</sub> = 2.0V |     | 625             |      |
| Δt/ΔV           | Δt/ΔV Input transition rise or fall rate | $V_{CC}$ = 4.5V        |     | 140             | ns/V |
|                 |  | $V_{CC}$ = 6.0V        |     | 85              |      |
| TA              | Operating free-air temperature           |                        | -40 | +125            | °C   |

Note: 6. Unused inputs should be held at  $V_{CC}$  or Ground.

# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Symbol Parameter | Test Conditions             |  |      | C to +85°C | T <sub>A</sub> = -40°C | to +125°C | 11   |      |
|------------------|-----------------------------|--|------|------------|------------------------|-----------|------|------|
|                  | Parameter                   | Parameter Test Conditions                                | Vcc  | Min        | Max                    | Min       | Max  | Unit |
|                  |                             |  | 2.0V | 1.5        |                        | 1.5       |      |      |
| VIH              | High-level Input<br>Voltage |  | 4.5V | 3.15       |                        | 3.15      |      | V    |
|                  | voltage                     |  | 6.0V | 4.2        |                        | 4.2       |      |      |
|                  |                             |  | 2.0V |            | 0.5                    |           | 0.5  |      |
| VIL              | Low-level input<br>voltage  |  | 4.5V |            | 1.35                   |           | 1.35 | V    |
|                  | voltage                     |  | 6.0V |            | 1.8                    |           | 1.8  |      |
|                  |                             | I <sub>OL</sub> = 20μA                                   | 2.0V |            | 0.1                    |           | 0.1  |      |
|                  |                             | I <sub>OL</sub> = 20μA                                   | 4.5V |            | 0.1                    |           | 0.1  |      |
| VoL              | Low-level Output<br>Voltage | I <sub>OL</sub> = 20µA                                   | 6.0V |            | 0.1                    |           | 0.1  | V    |
|                  | voltage                     | I <sub>OL</sub> = 4mA                                    | 4.5V |            | 0.33                   |           | 0.44 |      |
|                  |                             | I <sub>OL</sub> = 5.2mA                                  | 6.0V |            | 0.33                   |           | 0.44 |      |
| I <sub>OZ</sub>  | Z State<br>Leakage Current  | V <sub>O</sub> =0 to 6.0V<br>V <sub>I</sub> =GND or 6.0V | 6.0V |            | ± 5.0                  |           | ± 10 | μA   |
| II.              | Input Current               | V <sub>I</sub> =GND to 5.5V                              | 6.0V |            | ± 1                    |           | ± 1  | μA   |
| I <sub>CC</sub>  | Supply Current              | $V_{I} = GND \text{ or } V_{CC},$<br>$I_{O}=0$           | 6.0V |            | 20                     |           | 40   | μA   |



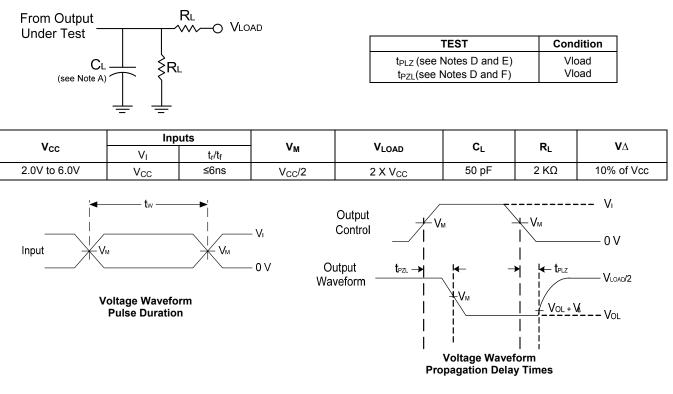
## **Switching Characteristics**

| Symbol Parameter               | Test   | Ma a                       | -    | T <sub>A</sub> = +25°0 | )   | -40°C to +85°C | -40°C to +125°C | Unit |      |
|--------------------------------|--|----------------------------|------|------------------------|-----|----------------|-----------------|------|------|
| Symbol                         | Parameter  | Conditions V <sub>CC</sub> | VCC  | Min                    | Тур | Max            | Max             | Max  | Unit |
|                                | $t_{PD}$ Propagation Figure 1<br>Delay A <sub>N</sub> to Y <sub>N</sub> C <sub>L</sub> = 50 pF | •                          | 2.0V | _                      | 25  | 90             | 115             | 125  |      |
| t <sub>PD</sub>                |  |                            | 4.5V | _                      | 9   | 18             | 23              | 27   | ns   |
|                                |  | CL = 50 pF                 | 6.0V | _                      | 7   | 15             | 20              | 23   |      |
|                                | <b>F</b> : 4   | Figure 1                   | 2.0V | _                      | 19  | 75             | 95              | 110  |      |
| t <sub>t</sub> Transition time | Figure 1<br>$C_L = 50 \text{ pF}$  | 4.5V                       | _    | 7                      | 15  | 19             | 22              | ns   |      |
|                                |  | 6.0V                       | _    | 6                      | 13  | 16             | 19              |      |      |

### Operating Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

|                 | Parameter                                 | Test Conditions           | V <sub>CC</sub> = 6V<br>Typ | Unit |
|-----------------|---|---------------------------|-----------------------------|------|
| C <sub>pd</sub> | Power dissipation<br>capacitance per gate | f = 1 MHz                 | 22                          | pF   |
| CI              | Input Capacitance                         | $V_{I} = V_{CC} - or GND$ | 4                           | pF   |

### **Parameter Measurement Information**



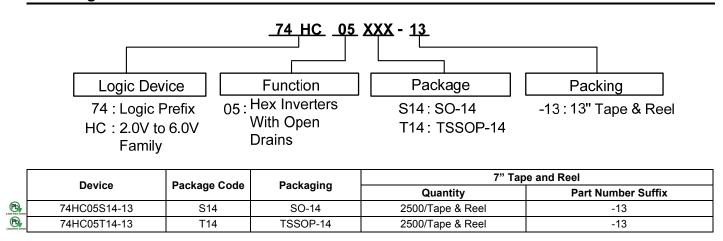
Notes: A. Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate  $\leq$  1 MHz.
- C.The inputs are measured one at a time with one transition per measurement.
- D. For the open drain device  $t_{\mathsf{PLZ}}$  and  $t_{\mathsf{PZL}}$  are the same as  $t_{\mathsf{PD.}}$
- E.  $t_{\text{PZL}}$  is measured at V<sub>M</sub>.
- F.  $t_{PLZ}\,$  is measured at V\_OL +V\_{\Delta.}
- D. A Thevenin equivalent load may be used in place of V<sub>CC</sub> X 2 and resistor divider.

#### Figure 1 Load Circuit and Voltage Waveforms

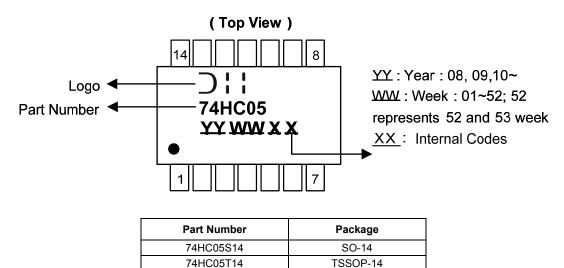


# **Ordering Information**



## **Marking Information**

(1) SO-14, TSSOP-14

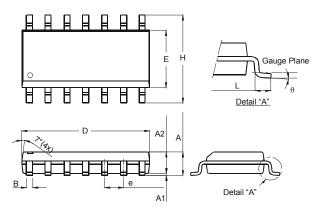




# Package Outline Dimensions (All dimensions in mm.)

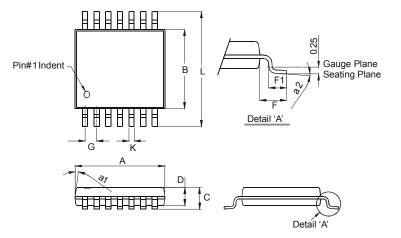
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

#### Package Type: SO-14



|        | SO-14    |         |  |  |  |  |
|--------|----------|---------|--|--|--|--|
| Dim    | Min      | Max     |  |  |  |  |
| Α      | 1.47     | 1.73    |  |  |  |  |
| A1     | 0.10     | 0.25    |  |  |  |  |
| A2     | 1.45     | Тур     |  |  |  |  |
| В      | 0.33     | 0.51    |  |  |  |  |
| D      | 8.53     | 8.74    |  |  |  |  |
| E      | 3.80     | 3.99    |  |  |  |  |
| е      | 1.27     | Тур     |  |  |  |  |
| Н      | 5.80     | 6.20    |  |  |  |  |
| L      | 0.38     | 1.27    |  |  |  |  |
| θ      | 0°       | 8°      |  |  |  |  |
| All Di | mensions | s in mm |  |  |  |  |

#### Package Type: TSSOP-14

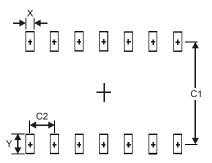


|         | TSSOP-14 |         |  |  |  |  |
|---------|----------|---------|--|--|--|--|
| Dim     | Min      | Max     |  |  |  |  |
| a1      | 7° (     | 4X)     |  |  |  |  |
| a2      | 0°       | 8°      |  |  |  |  |
| Α       | 4.9      | 5.10    |  |  |  |  |
| в       | 4.30     | 4.50    |  |  |  |  |
| C       |          | 1.2     |  |  |  |  |
| D       | 0.8      | 1.05    |  |  |  |  |
| F       | 1.00     | Тур     |  |  |  |  |
| F1      | 0.45     | 0.75    |  |  |  |  |
| G       | 0.65     | Тур     |  |  |  |  |
| κ       | 0.19     | 0.30    |  |  |  |  |
| L       | 6.40 Typ |         |  |  |  |  |
| All Dir | nensions | s in mm |  |  |  |  |

## **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for latest version.

#### Package Type: SO-14



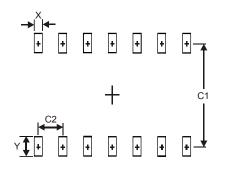
| Dimensions | Value (in mm) |
|------------|---------------|
| Х          | 0.60          |
| Y          | 1.50          |
| C1         | 5.4           |
| C2         | 1.27          |



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## Suggested Pad Layout (cont.)

Package Type: TSSOP-14



| Dimensions | Value (in mm) |
|------------|---------------|
| Х          | 0.45          |
| Y          | 1.45          |
| C1         | 5.9           |
| C2         | 0.65          |

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